

Technology & Industry Alliances

Available Technologies

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Tech ID: 31871

ADDITIONAL TECHNOLOGIES BY THESE INVENTORS

- Vertical Cavity Surface-Emitting Lasers with Continuous Wave Operation
- Eliminating Misfit Dislocations with In-Situ Compliant Substrate Formation
- Enhanced Light Extraction LED with a Tunnel Junction Contact Wafer Bonded to a Conductive Oxide
- Ultraviolet Laser Diode on Nano-Porous AlGaN template
- Improved Reliability & Enhanced Performance of III-Nitride Tunnel Junction Optoelectronic Devices
- ▶ (In,Ga,AI)N Optoelectronic Devices with Thicker Active Layers for Improved Performance
- ► Thermally Stable, Laser-Driven White Lighting Device
- Methods for Fabricating III-Nitride Tunnel Junction Devices
- Contact Architectures for Tunnel Junction Devices
- III-Nitride Tunnel Junction LED with High Wall Plug Efficiency
- A Method To Lift-Off Nitride Materials With Electrochemical Etch
- High-Intensity Solid State White Laser Diode
- Nitride Based Ultraviolet LED with an Ultraviolet Transparent Contact

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